

# SANYO Semiconductors DATA SHEET

## 2SD1229 — NPN Epitaxial Planar Silicon Darlington Transistor Driver Applications

## **Applications**

• Motor drivers, printer hammer drivers, relay drivers, voltage reguraltor control.

#### **Features**

- · High DC current gain.
- · High current capacity and wide ASO.
- · Low saturation voltage.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		70	V
Collector-to-Emitter Voltage	VCEO		60	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		10	Α
Collector Current (Pulse)	ICP		15	Α
Collector Dissipation	De		2.5	W
	PC	Tc=25°C	60	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =40V, I <sub>E</sub> =0A			0.1	mA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =5V, I <sub>C</sub> =0A			3.0	mA
DC Current Gain	hFE	V <sub>CE</sub> =2V, I <sub>C</sub> =5A	2000	5000		
Gain-Bandwidth Product	fŢ	VCE=5V, IC=5A		20		MHz

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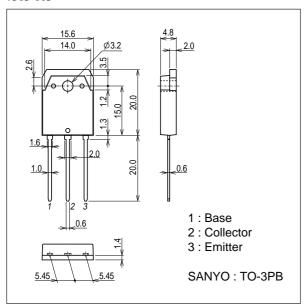
## 2SD1229

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=5A, IB=10mA		0.9	1.5	V
Base-to-Emitterr Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =5A, I <sub>B</sub> =10mA			2.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=5mA, IE=0A	70			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=50mA, RBE=∞	60			V
Turn-ON Time	ton	See specified Test Circuit		0.6		μS
Storage Time	tstg	See specified Test Circuit		3.0		μS
Fall Time	tf	See specified Test Circuit		1.8		μs

## **Package Dimensions**

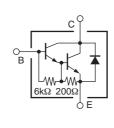
unit : mm (typ) 7503-003

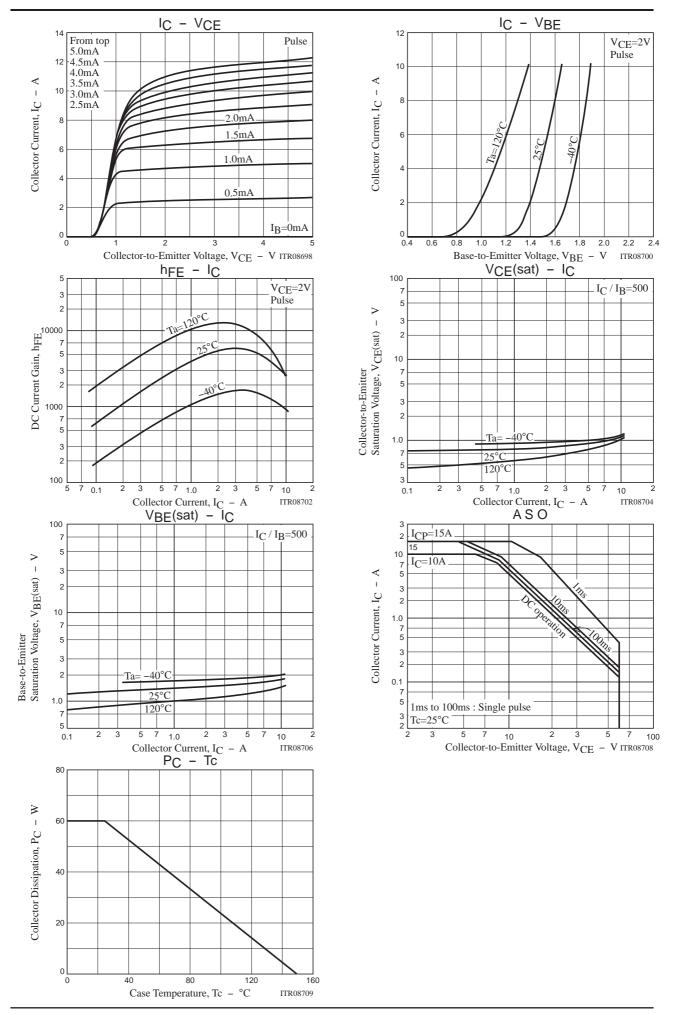


## **Switching Time Test Circuit**

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## **Electrical Connection**





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